

Octal D-type flip-flop with enable

74ABT377

FEATURES

- Ideal for addressable register applications
- 8-bit positive edge-triggered register
- Enable for address and data synchronization applications
- Output capability: +64mA/-32mA
- Latch-up protection exceeds 500mA per Jedec JC40.2 Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model
- Power-up reset

DESCRIPTION

The 74ABT377 high-performance BiCMOS device combines low static and dynamic power dissipation with high speed and high output drive.

The 74ABT377 has 8 edge-triggered D-type flip-flops with individual D inputs and Q outputs. The common buffered clock (CP) input loads all flip-flops simultaneously when the Enable (E) input is Low.

The register is fully edge triggered. The state of each D input, one set-up time before the Low-to-High clock transition, is transferred to the corresponding flip-flop's Q output.

The E input must be stable one setup time prior to the Low-to-High clock transition for predictable operation.

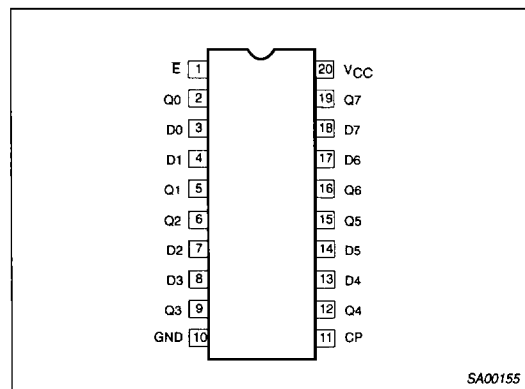
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS $T_{amb} = 25^{\circ}\text{C}; \text{GND} = 0\text{V}$	TYPICAL	UNIT
t_{PLH} t_{PHL}	Propagation delay CP to Qn	$C_L = 50\text{pF}; V_{CC} = 5\text{V}$	5.3	ns
C_{IN}	Input capacitance	$V_I = 0\text{V} \text{ or } V_{CC}$	4	pF
I_{CCH}	Total current supply	Outputs High; $V_{CC} = 5.5\text{V}$	500	nA

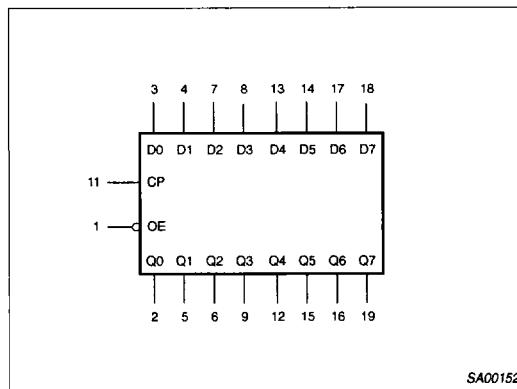
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
20-Pin Plastic DIP	-40°C to +85°C	74ABT377 N	74ABT377 N	SOT146-1
20-Pin plastic SO	-40°C to +85°C	74ABT377 D	74ABT377 D	SOT163-1
20-Pin Plastic SSOP Type II	-40°C to +85°C	74ABT377 DB	74ABT377 DB	SOT339-1
20-Pin Plastic TSSOP Type I	-40°C to +85°C	74ABT377 PW	74ABT377PW DH	SOT360-1

PIN CONFIGURATION



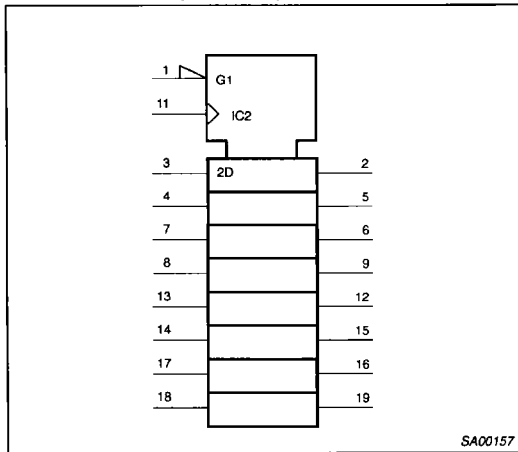
LOGIC SYMBOL



Octal D-type flip-flop with enable

74ABT377

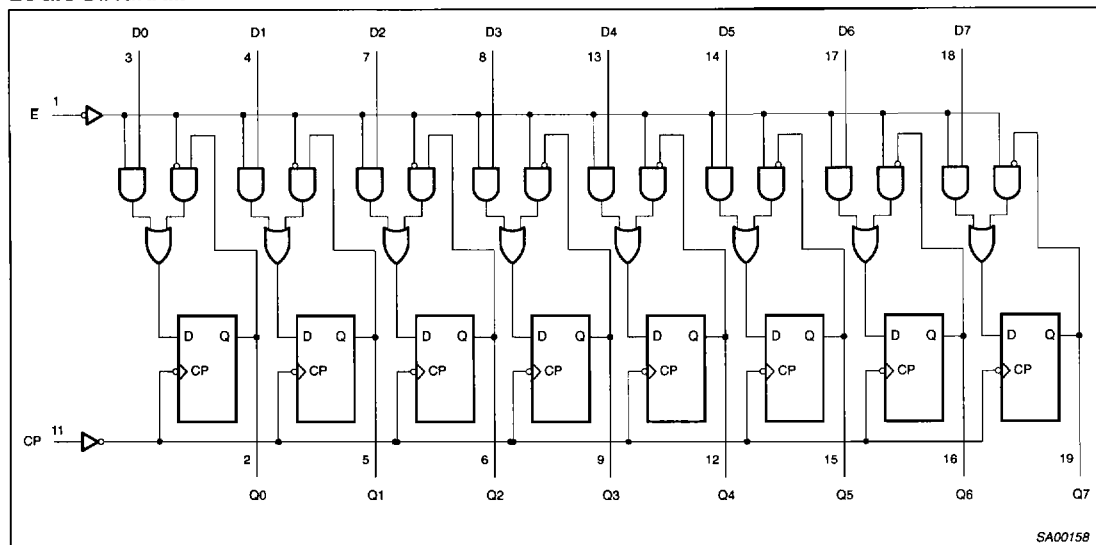
LOGIC SYMBOL (IEEE/IEC)



PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1	E	Enable input (active-Low)
3, 4, 7, 8, 13, 14, 17, 18	D0-D7	Data inputs
2, 5, 6, 9, 12, 15, 16, 19	Q0-Q7	Data outputs
11	CP	Clock Pulse input (active rising edge)
10	GND	Ground (0V)
20	V _{CC}	Positive supply voltage

LOGIC DIAGRAM



Octal D-type flip-flop with enable

74ABT377

FUNCTION TABLE

INPUTS			OUTPUTS	OPERATING MODE
E	CP	D _n	Q _n	
l	↑	h	H	Load "1"
l	↑	l	L	Load "0"
h	↑	X	no change no change	Hold (do nothing)
	X	X		

H = High voltage level

h = High voltage level one set-up time prior to the Low-to-High clock transition

L = Low voltage level

l = Low voltage level one set-up time prior to the Low-to-High clock transition

X = Don't care

↑ = Low-to-High clock transition

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +7.0	V
I _{IK}	DC input diode current	V _I < 0	-18	mA
V _I	DC input voltage ³		-1.2 to +7.0	V
I _{OK}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	output in Off or High state	-0.5 to +5.5	V
I _{OUT}	DC output current	output in Low state	128	mA
T _{stg}	Storage temperature range		-65 to 150	°C

NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMITS		UNIT
		MIN	MAX	
V _{CC}	DC supply voltage	4.5	5.5	V
V _I	Input voltage	0	V _{CC}	V
V _{IH}	High-level input voltage	2.0		V
V _{IL}	Low-level input voltage		0.8	V
I _{OH}	High-level output current		-32	mA
I _{OL}	Low-level output current		64	mA
Δt/Δv	Input transition rise or fall rate	0	5	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

Octal D-type flip-flop with enable

74ABT377

DC ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS					UNIT
			T _{amb} = +25°C			T _{amb} = -40°C to +85°C		
			MIN	TYP	MAX	MIN	MAX	
V _{IK}	Input clamp voltage	V _{CC} = 4.5V; I _{IK} = -18mA		-0.9	-1.2		-1.2	V
V _{OH}	High-level output voltage	V _{CC} = 4.5V; I _{OH} = -3mA; V _I = V _{IL} or V _{IH}	2.5	2.9		2.5		V
		V _{CC} = 5.0V; I _{OH} = -3mA; V _I = V _{IL} or V _{IH}	3.0	3.4		3.0		V
		V _{CC} = 4.5V; I _{OH} = -32mA; V _I = V _{IL} or V _{IH}	2.0	2.4		2.0		V
V _{OL}	Low-level output voltage	V _{CC} = 4.5V; I _{OL} = 64mA; V _I = V _{IL} or V _{IH}		0.42	0.55		0.55	V
V _{RST}	Power-up output low voltage ³	V _{CC} = 5.5V; I _O = 1mA; V _I = GND or V _{CC}		0.13	0.55		0.55	V
I _I	Input leakage current	V _{CC} = 5.5V; V _I = GND or 5.5V		±0.01	±1.0		±1.0	µA
I _{OFF}	Power-off leakage current	V _{CC} = 0.0V; V _O or V _I ≤ 4.5V		±5.0	±100		±100	µA
I _{CEX}	Output High leakage current	V _{CC} = 5.5V; V _O = 5.5V; V _I = GND or V _{CC}		5.0	50		50	µA
I _O	Output current ¹	V _{CC} = 5.5V; V _O = 2.5V	-50	-100	-180	-50	-180	mA
I _{CCH}	Quiescent supply current	V _{CC} = 5.5V; Outputs High, V _I = GND or V _{CC}		0.5	250		250	µA
I _{CCL}		V _{CC} = 5.5V; Outputs Low, V _I = GND or V _{CC}		24	30		30	mA
ΔI _{CC}	Additional supply current per input pin ²	V _{CC} = 5.5V; one input at 3.4V, other inputs at V _{CC} or GND		0.5	1.5		1.5	mA

NOTES:

- Not more than one output should be tested at a time, and the duration of the test should not exceed one second.
- This is the increase in supply current for each input at 3.4V.
- For valid test results, data must not be loaded into the flip-flops (or latches) after applying the power.

AC CHARACTERISTICS

GND = 0V, t_R = t_F = 2.5ns, C_L = 50pF, R_L = 500Ω

SYMBOL	PARAMETER	WAVEFORM	LIMITS					UNIT
			T _{amb} = +25°C V _{CC} = +5.0V			T _{amb} = -40 to +85°C V _{CC} = +5.0V ±0.5V		
			MIN	TYP	MAX	MIN	MAX	
f _{MAX}	Maximum clock frequency	1	150	200		150		MHz
t _{PLH} t _{PHL}	Propagation delay CP to Qn	1	2.2	4.5	6.0	2.2	6.5	ns
			3.1	5.3	6.8	3.1	7.3	

Octal D-type flip-flop with enable

74ABT377

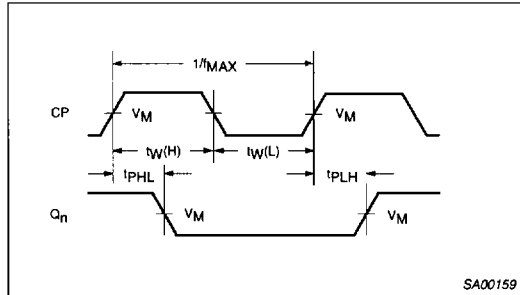
AC SETUP REQUIREMENTS

GND = 0V, $t_{\text{P}} = t_{\text{F}} = 2.5\text{ns}$, $C_{\text{L}} = 50\text{pF}$, $R_{\text{L}} = 500\Omega$

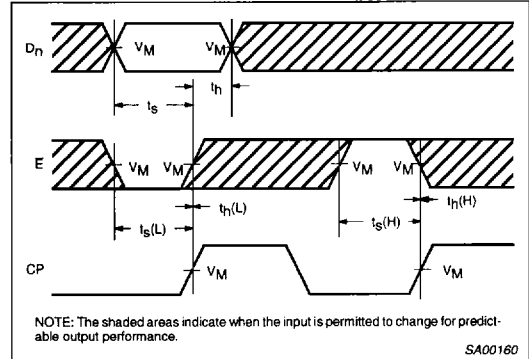
SYMBOL	PARAMETER	WAVEFORM	LIMITS			UNIT
			$T_{\text{amb}} = +25^{\circ}\text{C}$ $V_{\text{CC}} = +5.0\text{V}$		$T_{\text{amb}} = -40 \text{ to } +85^{\circ}\text{C}$ $V_{\text{CC}} = +5.0\text{V} \pm 0.5\text{V}$	
			MIN	TYP	MIN	
$t_{\text{s}}(\text{H})$ $t_{\text{s}}(\text{L})$	Setup time, High or Low Dn to CP	2	2.0 2.0	0.9 0.7	2.0 2.0	ns
$t_{\text{h}}(\text{H})$ $t_{\text{h}}(\text{L})$	Hold time, High or Low Dn to CP	2	1.0 1.0	-0.6 -0.6	1.0 1.0	ns
$t_{\text{s}}(\text{H})$ $t_{\text{s}}(\text{L})$	Setup time, High or Low E to CP	2	3.0 3.0	1.6 1.2	3.0 3.0	ns
$t_{\text{h}}(\text{H})$ $t_{\text{h}}(\text{L})$	Hold time, High or Low E to CP	2	1.0 1.0	-0.9 -0.6	1.0 1.0	ns
$t_{\text{pw}}(\text{H})$ $t_{\text{pw}}(\text{L})$	Clock Pulse width High or Low	1	3.3 3.3	2.2 1.3	3.3 3.3	ns

AC WAVEFORMS

$V_{\text{M}} = 1.5\text{V}$, $V_{\text{IN}} = \text{GND to } 3.0\text{V}$



Waveform 1. Propagation Delay, Clock Input to Output, Clock Pulse Width and Maximum Clock Frequency



Waveform 2. Data and Enable Setup and Hold Times

Octal D-type flip-flop with enable

74ABT377

TEST CIRCUIT AND WAVEFORM

Test Circuit for 3-State Outputs

Input Pulse Definition

$V_M = 1.5V$

SWITCH POSITION

TEST	SWITCH
All	open

DEFINITIONS

R_L = Load resistor; see AC CHARACTERISTICS for value.

C_L = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

FAMILY	INPUT PULSE REQUIREMENTS				
	Amplitude	Rep. Rate	t_w	t_R	t_F
74ABT	3.0V	1MHz	500ns	2.5ns	2.5ns

SA00057